

HIGH PERFORMANCE TRIAC

FEATURES

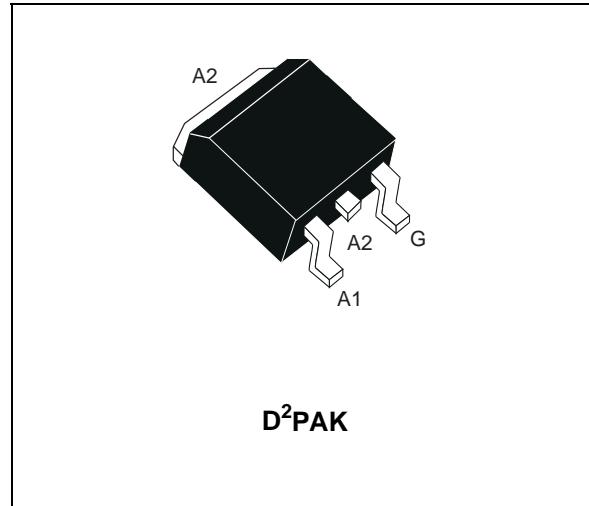
- HIGH COMMUTATION PERFORMANCES
- SNUBBERLESS™ TECHNOLOGY
- HIGH NOISE IMMUNITY (dV/dt)
- HIGH I_{TSM}

DESCRIPTION

The T1635-600G and T1650-600G triacs are using high performance SNUBBERLESS technology.

They are intended for AC control applications using surface mount technology.

These devices are perfectly suited where high commutation and surge performances are required.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
V_{DRM} V_{RRM}	Repetitive peak off-state voltage	600	V
$I_{T(RMS)}$	RMS on-state current (360° conduction angle)	16	A
I_{TSM}	Non repetitive surge peak on-state current (T_j initial = 25°C)	$t_p = 8.3\text{ms}$	170
		$t_p = 10 \text{ ms}$	160
I^2t	I^2t Value for fusing	128	A^2s
dl/dt	Critical rate of rise of on-state current $I_G = 500 \text{ mA}$ $dl_G/dt = 1 \text{ A}/\mu\text{s}$.	Repetitive $F = 50 \text{ Hz}$	20
		Non Repetitive	100
T_{stg} T_j	Storage temperature range Operating junction temperature range	- 40, + 150 - 40, + 125	$^\circ\text{C}$
T	Maximum temperature for soldering during 10s	260	$^\circ\text{C}$

T1635-600G / T1650-600G

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient ($S=1\text{cm}^2$)	45	°C/W
R _{th(j-c)}	Junction to case for DC	1.6	°C/W
R _{th(j-c)}	Junction to case for AC 360° conduction angle (F=50Hz)	1.2	°C/W

GATE CHARACTERISTICS (maximum values)

P_{G (AV)}= 1 W P_{GM} = 10 W (tp = 20 μs) I_{GM} = 4 A (tp = 20 μs)

ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions		Quadrant		T1635	T1650	Unit
I _{GT}	V _D =12V (DC) R _L =33Ω	T _j = 25°C	I-II-III	MIN	2		mA
				MAX	35	50	
V _{GT}	V _D =12V (DC) R _L =33Ω	T _j = 25°C	I-II-III	MAX	1.3		V
V _{GD}	V _D =V _{DRM} R _L =3.3kΩ	T _j = 125°C	I-II-III	MIN	0.2		V
I _H *	I _T = 100mA Gate open	T _j = 25°C		MAX	35	50	mA
I _L	I _G = 1.2 I _{GT}	T _j = 25°C	I-III	MAX	50	60	mA
			II	MAX	80	120	
V _{TM} *	I _{TM} = 22.5A tp= 380μs	T _j = 25°C		MAX	1.5		V
I _{DRM}	V _D = V _{DRM}	T _j = 25°C		MAX	5		μA
I _{RRM}	V _R = V _{RRM}		T _j = 125°C	MAX	2		mA
dV/dt *	Linear slope up to V _D =67%V _{DRM} Gate open	T _j = 125°C		MIN	500	1000	V/μs
(dI/dt)c *	Without snubber	T _j = 125°C		MIN	8.5	14	A/ms

* For either polarity of electrode A2 voltage with reference to electrode A1.

ORDERING INFORMATION Add "-TR" suffix for Tape & Reel shipment

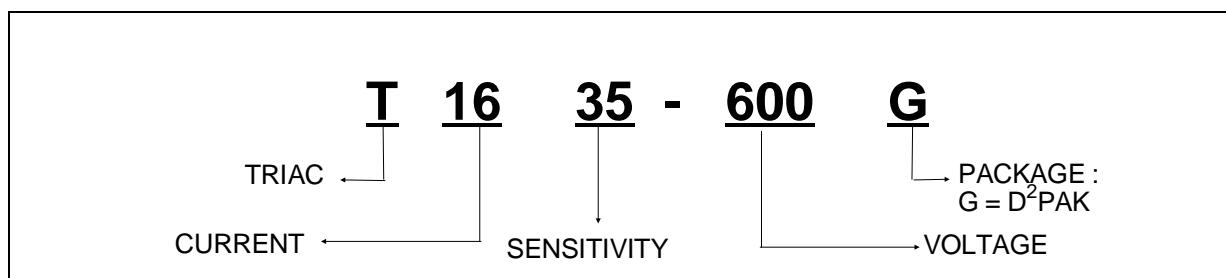


Fig. 1: Maximum power dissipation versus RMS on-state current.

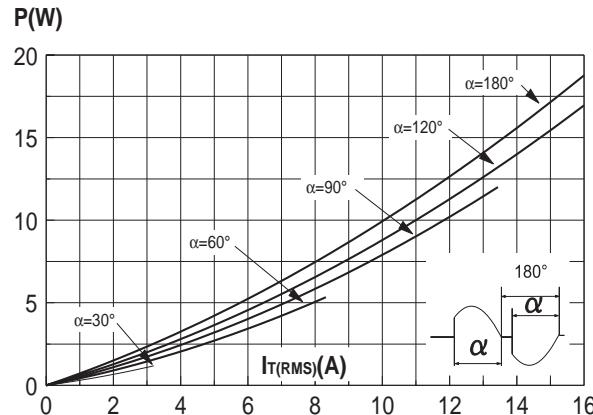


Fig. 3: RMS on-state current versus case temperature.

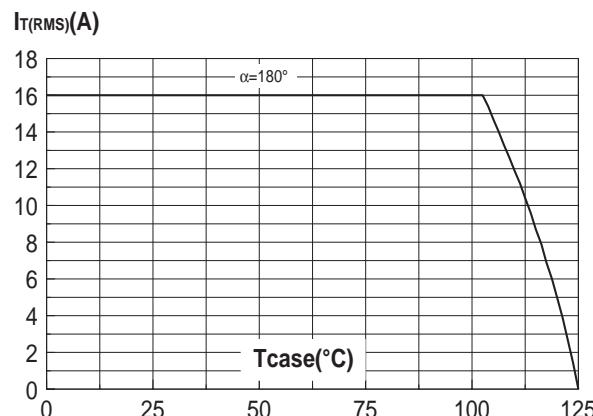


Fig. 5: Relative variation of gate trigger current and holding current versus junction temperature (typical values).

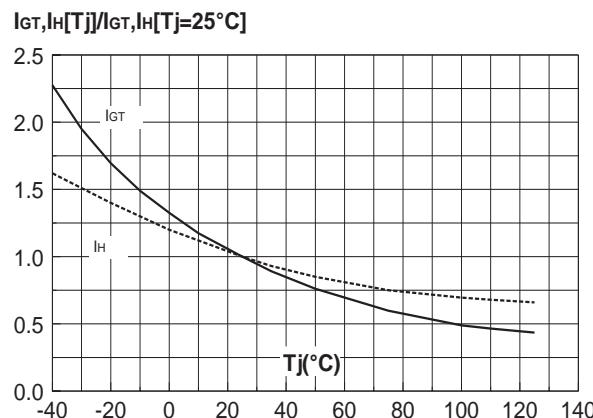


Fig. 2: Correlation between maximum power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink+contact.

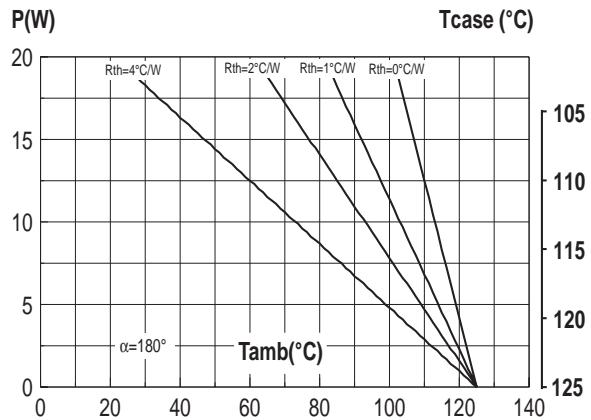


Fig. 4: Relative variation of thermal impedance versus pulse duration.

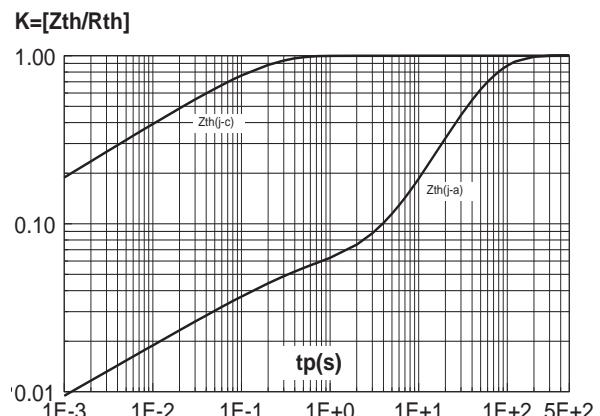
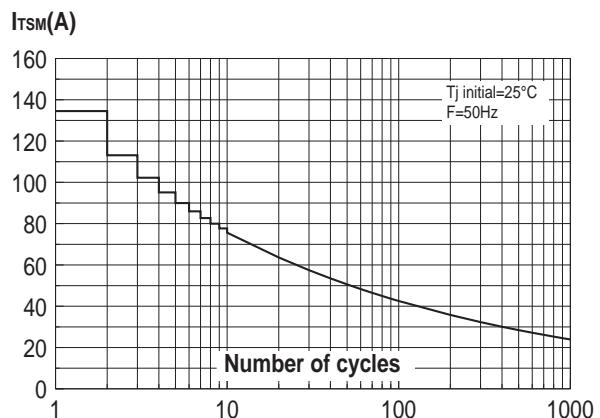


Fig. 6: Non repetitive surge peak on-state current versus number of cycles.



T1635-600G / T1650-600G

Fig. 7: Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t .

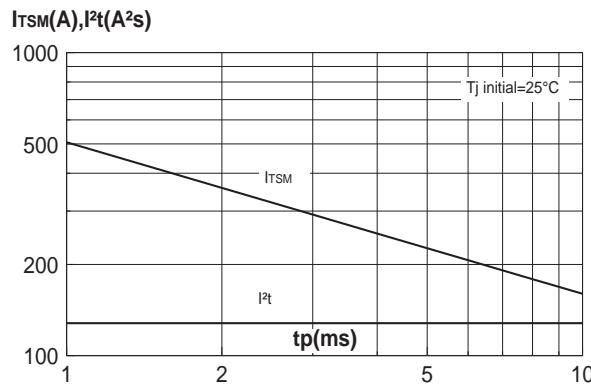


Fig. 9: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: $35\mu\text{m}$).

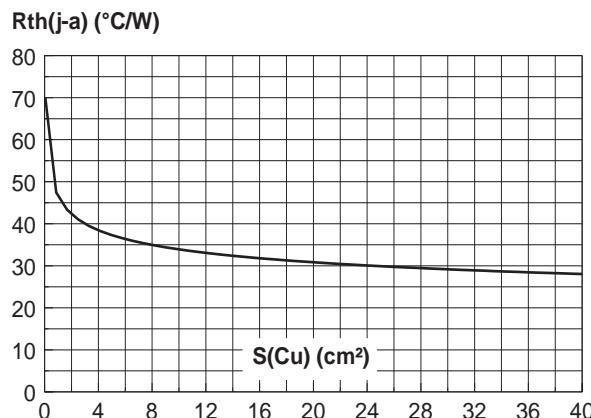


Fig. 8: On-state characteristics (maximum values).

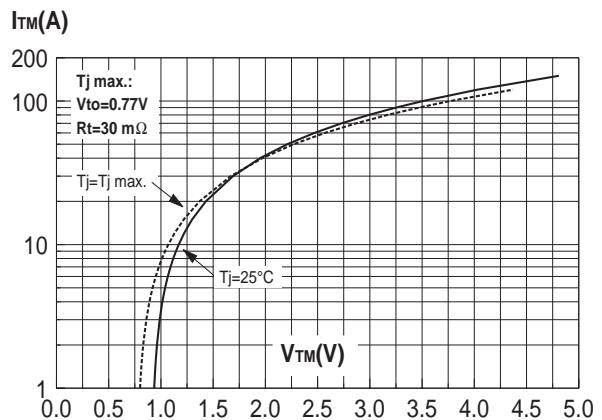
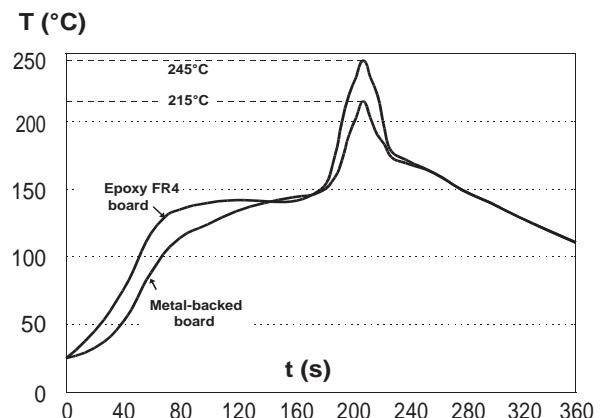


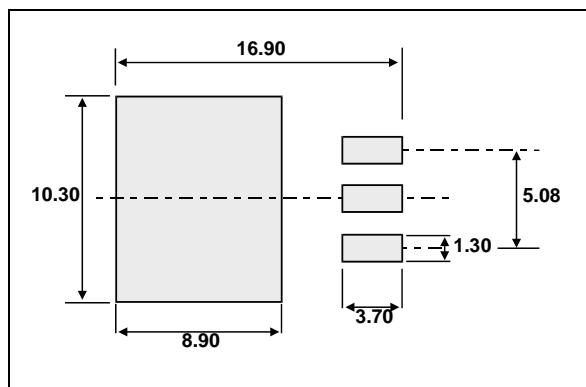
Fig. 10: Typical reflow soldering heat profile, either for mounting on FR4 or metal-backed boards.



PACKAGE MECHANICAL DATA
D²PAK

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.169		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.70		0.93	0.027		0.037
B2	1.25	1.40		0.048	0.055	
C	0.45		0.60	0.017		0.024
C2	1.21		1.36	0.047		0.054
D	8.95		9.35	0.352		0.368
E	10.00		10.28	0.393		0.405
G	4.88		5.28	0.192		0.208
L	15.00		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.40		1.75	0.055		0.069
R		0.40			0.016	
V2	0°		8°	0°		8°

FOOT PRINT DIMENSIONS (in millimeters)



MARKING

TYPE	MARKING
T1635-600G	T1635 600G
T1650-600G	T1650 600G

PACKING

Tube : 50 units

Tape and reel : 500 units

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